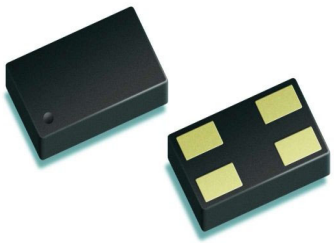
RF ESD Protection Diodes



- ESD protection of RF antenna / interfaces or ultra high speed data lines acc. to:
  IEC61000-4-2 (ESD): ± 20 kV (air / contact)
  IEC61000-4-4 (EFT): 40 A (5/50 ns)
  IEC61000-4-5 (surge): 10 A (8/20 µs)
- Very low line capacitance: 0.8 pF @ 1 GHz (0.4 pF per diode)
- Ultra low series inductance: 0.4 nH per diode
- Very low clamping voltage
- Ultra small leadless package 1.2 x 0.8 x 0.39 mm
- Pb-free (RoHS compliant) package

Applications in anti-parallel configuration

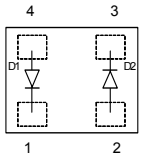
- For low RF signal levels without superimposed DC voltage: e.g. GPS, XM-Radio, Sirius, DVB, DMB, DAB, Remote Keyless Entry

Applications in rail-to-rail configuration

- For high RF signal levels or low RF signal levels with superimposed DC voltage: e.g. HDMI, S-ATA, Gbit Ethernet
- For more technical details on ESD and Antenna protection please refer to Application Note No.103 on **www.infineon.com/tvsdiodes**

RoHS

ESD0P8RFL



Type	Package	Configuration	Marking
ESD0P8RFL	TSLP-4-7	anti-parallel	E8

Maximum Ratings at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Value	Unit
ESD contact discharge[1)]	V_{ESD}	20	kV
Peak pulse current (t_p = 8 / 20 µs)[2)]	I_{pp}	10	A
Operating temperature range	T_{op}	-55...150	°C
Storage temperature	T_{stg}	-65...150	

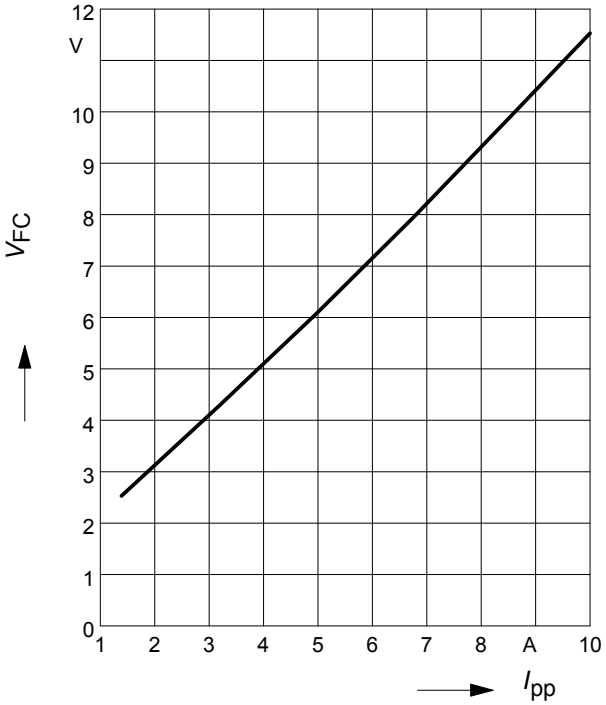
Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Characteristics -					
Reverse working voltage[3)]	V_{RWM}	-	-	50	V
Reverse current[3)] V_R = 50 V	I_R	-	-	100	nA
Forward clamping voltage[2)] I_{PP} = 10 A	V_{FC}	-	12	15	V
Line capacitance[4)] V_R = 0 V, f = 1 GHz	C_T	-	0.8	-	pF
Series inductance (per diode)	L_S	-	0.4	-	nH

[1]V_{ESD} according to IEC61000-4-2, only valid in anti-parallel or rail-to-rail connection.
Please refer to the application examples.
[2]I_{pp} according to IEC61000-4-5, only valid in anti-parallel or rail-to-rail connection.
Please refer to the application examples.
[3]Only valid in rail-to-rail configuration with $V_{CC} \geq V_{RWM}$
[4]Total capacitance line to ground (2 diodes in parallel)

Forward clamping voltage $V_{FC} = f(I_{PP})$

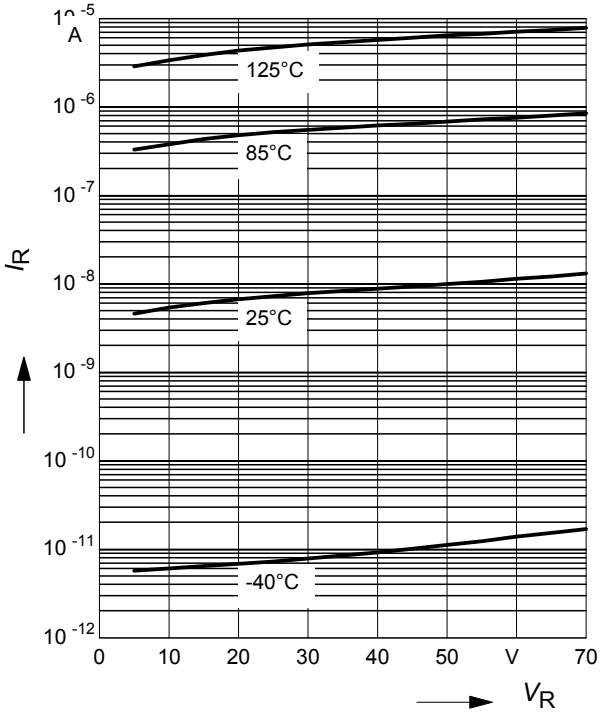
t_p = 8 / 20 µs



Reverse current $I_R = f(V_R)$

T_A = Parameter

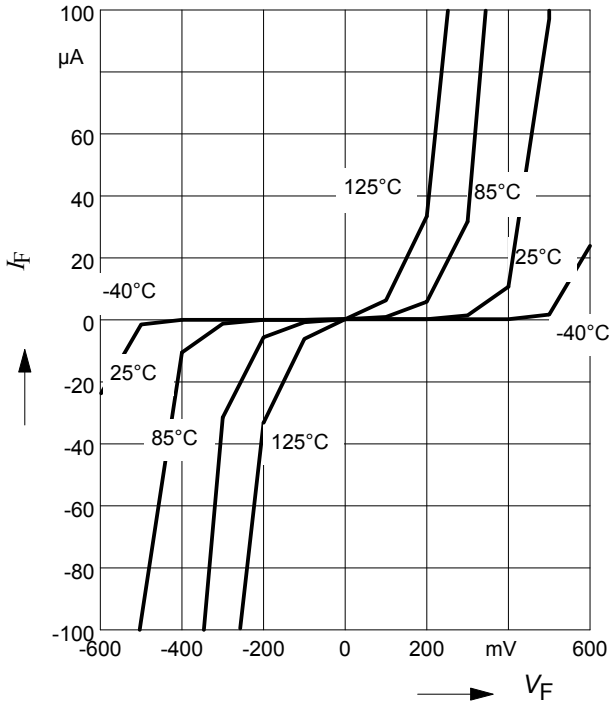
leakage in rail-to-rail configuration



Forward current $I_F = f(V_F)$

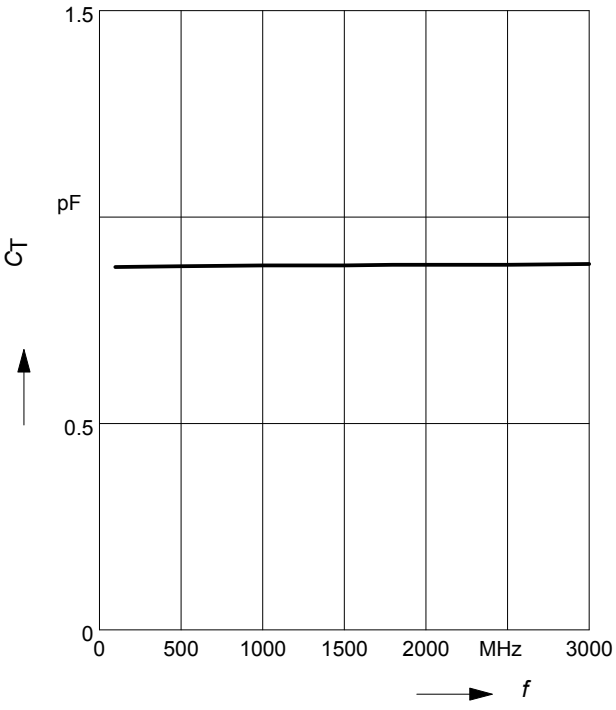
T_A = Parameter

leakage in anti-parallel configuration



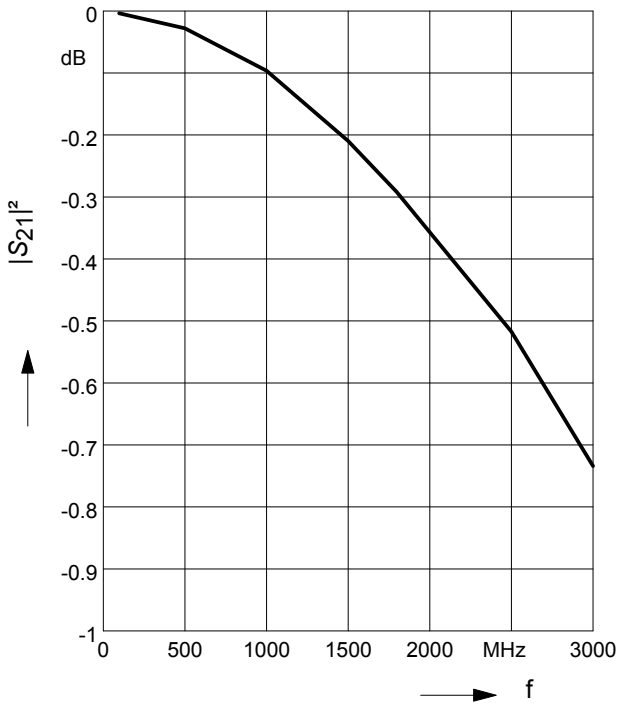
Line capacitance $C_T = f$ (f)

V_R = 0 V



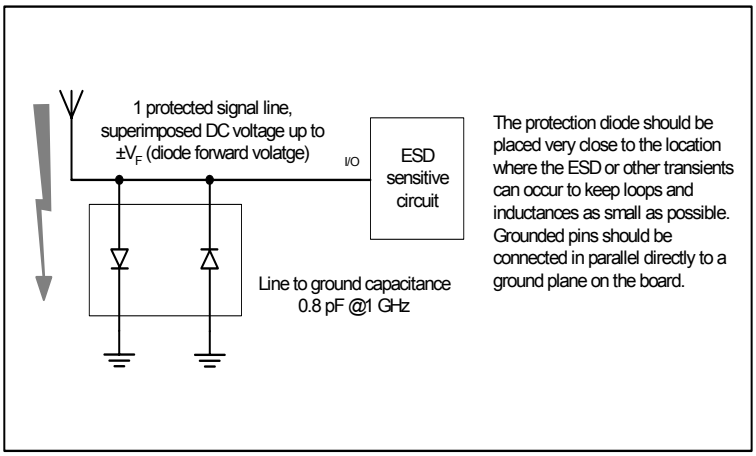
Insertion loss $I_L = -|S_{21}|^2 = f(f)$

V_R = 0 V, Z = 50 Ω



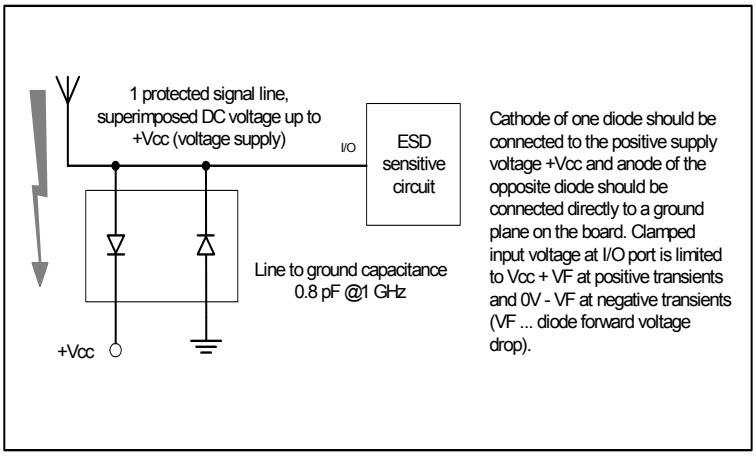
1. Application example

1 RF signal channel, anti-parallel configuration,
please refer also to Application Note No.103

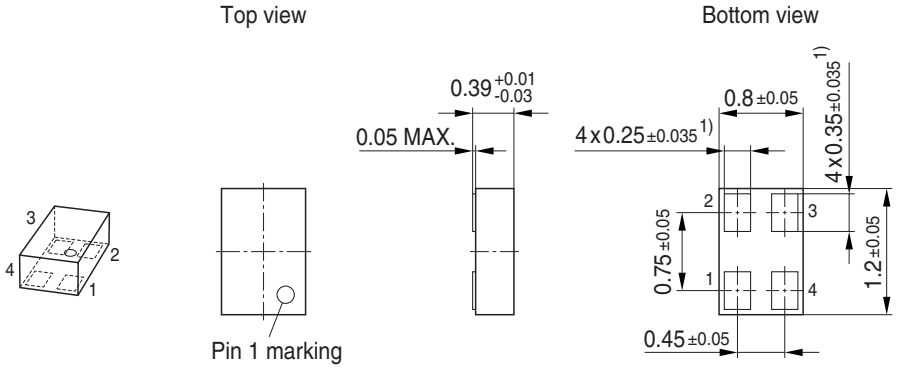


2. Application example

1 RF signal channel, rail-to-rail configuration



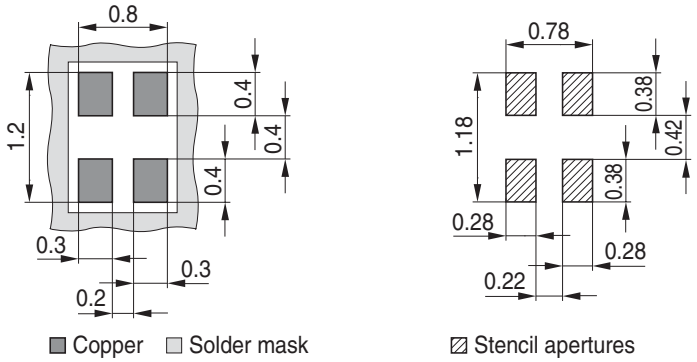
Package Outline



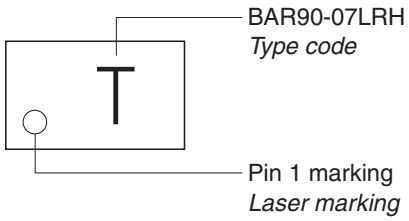
1) Dimension applies to plated terminal

Foot Print

For board assembly information please refer to Infineon website "Packages"

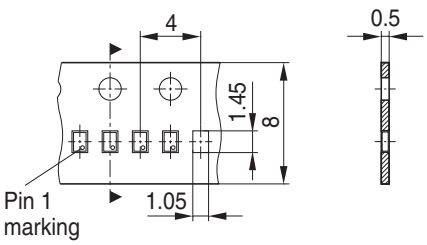


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel



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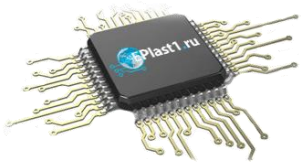
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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